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Intermetallic compounds M_2Pt ($M = Al, Ga, In, Sn$) in the oxygen evolution reaction†

Ana María Barrios Jiménez, Alim Ormeci, Ulrich Burkhardt, Simone G. Altendorf, Felix Kaiser, Igor Veremchuk, Gudrun Auffermann, Yuri Grin and Iryna Antonyshyn*

Pt-based intermetallic compounds M_2Pt with *anti*- CaF_2 type of crystal structure and counterpart elements (M) from groups 13 (Al, Ga, In) and 14 (Sn) were studied as electrocatalysts for the oxygen evolution reaction (OER) in acidic media. Polar covalent bonding $M-Pt$ with substantial charge transfer makes the difference between M_2Pt and elemental platinum. The compounds M_2Pt ($M = Al, Ga, In$) possess enhanced OER activity compared to elemental Pt and it improves during the partial on-going leaching of the M component. Therefore, the M_2Pt compounds act as precursors for formation of OER-active M_xPt_{1-x} layers.

Introduction

Electrocatalysts support the sufficient kinetics of the electrochemical processes for the production of energy-carrier substances in a sustainable way.^{1–5} Among them, hydrogen is the most promising clean fuel, since its conversion brings the largest amount of energy per weight unit.^{6,7} Therefore, development of the suitable catalysts for water splitting process, focusing on the anodic oxygen evolution reaction (OER) as rate-limiting one,^{8–11} is the main target for many studies nowadays.

Considering the extremely oxidative conditions of OER, not only the activity, but also the stability of the catalysts under working conditions is a crucial factor for their use. Both properties largely depend on the electronic and structural features of the electrode materials.^{12–16} Those properties are determined by both, the catalytically active transition metal and the counterpart elements,^{2,17} and, therefore, can be modified by changing the components, which yields different catalytic performance of the resultant compounds.

Currently, Ir- and Ru- based materials, *e.g.* $IrO_x/SrIrO_3$ or $Cr_{0.6}Ru_{0.4}O_2$,^{18,19} are considered as the outstanding electrocatalysts for the OER.^{20–22} The high OER activity of Ir- and Ru-based electrocatalysts is attributed to their near optimal binding energy of the OER-intermediates O_{ad} and OOH_{ad} .^{2,23,24}

However, looking at catalyst stability under OER conditions, platinum is the most stable one against dissolution.^{25,26} Furthermore, it is known that introducing Pt atoms into the structure of other active materials leads to the improved stability limits of such electrocatalysts.^{27–29} The OER activity can

be improved through increase of the electrochemically active surface area *via* shaping, using various supports³⁰ and/or synthesis of nanoparticles²⁰ or porous Pt.^{31,32} However, the use of intermetallic compounds, combining Pt with other metals, to increase its inherent OER activity is represented scarcely in the literature.³³ The intermetallic compound with the modified electronic structure^{13,14,34} reveals different electrocatalytic activity. Combining platinum, as a catalytic center stable against the dissolution, with Al as the main group element was recognized as a good strategy to improve the OER activity of such electrode materials. The intermetallic compound Al_2Pt (*anti*- CaF_2 type of crystal structure) shows a promising OER performance, proving that the strategy to enhance OER activity by modifying the Pt electronic state lowers significantly the OER overpotential compared to elemental Pt.³⁵

Following these thoughts, the influence of the electronic factor on the chemical behaviour of Pt-based materials and their OER performance has been studied. To avoid the influence of the geometrical factor and address mainly the effect of the chemical nature of the counterpart element on the reaction rates, this study was performed on the isostructural compounds M_2Pt ($M = Al, Ga, In, Sn$) with *anti*- CaF_2 type of crystal structure.

Experimental

Preparation

For the synthesis of M_2Pt ($M = Al, Ga, In, Sn$), platinum slugs (Alfa Aesar, 99.99%) were mixed with aluminum shots (Chempur, 99.9999%), gallium pieces (Chempur, 99.9999%), indium granules (Roth, >99.97%) or tin shots (Alfa Aesar, 99.9999%), respectively. The atomic ratio between the components was equal to 2 : 1 only in case of Sn_2Pt , in the synthesis of other compounds compositions were slightly different (*i.e.*, 68.2 : 31.8 for Al_2Pt ; 66.17 : 33.83 for Ga_2Pt and 65.67 : 34.33 for In_2Pt) to

Max-Planck-Institut für Chemische Physik fester Stoffe, Nöthnitzer Str. 40, 01187 Dresden, Germany. E-mail: Iryna.Antonyshyn@cpfs.mpg.de

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ensure the single-phase character of the products. The Al₂Pt sample was prepared by arc melting of initial components on a water-cooled copper mold under argon atmosphere. To achieve homogeneity, the sample was re-melted three times. Compounds M₂Pt (M = Ga, In, Sn) were synthesized *via* reacting elements in the high frequency furnace in glassy carbon crucibles under argon atmosphere. The mass losses were 0.15, 0.01, 0.03 and 0.01% for Al₂Pt, Ga₂Pt, In₂Pt and Sn₂Pt, respectively. The ingots after melting were placed in alumina crucibles and sealed into Ta containers, which were enclosed into quartz ampoules under vacuum. The homogenization annealing of M₂Pt (M = Al, Ga, In, Sn) was carried out for seven days in resistance furnaces at 1000 °C, 870 °C, 950 °C and 710 °C, respectively. The annealing temperatures for M₂Pt compounds were chosen based on the formation reactions and corresponding temperatures, taken from the phase diagrams of the respective binary M–Pt systems.^{36–39} Afterwards, samples were quenched in the iced water with breaking of quartz ampoules.

To manufacture the specimens for the electrochemical measurements (cylinders 8 mm in diameter and 3–4 mm high), spark plasma sintering (SPS, 515 ET Sinter Lab, Fuji Electronic Industrial Co. Ltd.) was used. The ingots were crushed, grinded and filled into a graphite die, the graphite foil was used to avoid a direct contact between sample and die's walls. The heating by pulsed direct electrical current with low voltages was carried out with a rate of 100 °C min^{−1} up to maximum temperature ($T_{\max}$) of 1000, 800, 900 and 600 °C in case of Al₂Pt, Ga₂Pt, In₂Pt and Sn₂Pt, respectively, followed by dwelling at $T_{\max}$ and uniaxial pressure of 80 MPa for 10 min. After SPS, pellets were polished using different SiC grinding papers and, finally, diamond solutions (diamond particle size 3, 1, $\frac{1}{4}$ μm).

Characterization

Powder X-ray diffraction (PXRD) patterns of as-synthesized samples were collected in transmission mode on a Huber Imaging Plate Guinier Camera G670 (CuKα₁ radiation, $\lambda = 1.540562$ Å). The phase analysis was performed *via* comparison of experimental PXRD patterns with theoretically calculated ones using program WinXPOW.⁴⁰ For lattice parameter determination, LaB₆ ($a = 4.1569$ Å) was used as internal standard for PXRD data collection and software package WinCSD⁴¹ was employed for data evaluation.

Scanning electron microscopy SEM (JEOL JSM-7800F) with energy-dispersive X-ray spectroscopy (EDXS) system (Quantax 400, Bruker, Silicon-Drift-Detector (SDD)) was performed to control the quality and homogeneity of the prepared samples as well as to inspect the changes of the material after electrochemical treatments. Platinum concentration mapping of the surfaces was obtained using the intensities of the Pt Mα lines with the acceleration voltage of 27 kV. To obtain the semi-quantitative M : Pt ratios at different depths of the material, EDXS data were collected with acceleration voltages of 5, 10 and 27 kV. Depth-dependent changes in composition were evaluated *via* comparison of the detected X-ray intensities of the Al Kα, Ga Lα, In Lα and Sn Lα lines with the calculated ones for homogeneous samples, normalizing all intensities to a Pt Mα line

intensity equal to 1. Optical micrographs were taken under a light microscope (Axioplan 2, Zeiss) in bright-field, polarised light and with differential interferential contrast at various magnifications.

To characterize the electronic state of the elements, the samples were analyzed by X-ray photoelectron spectroscopy (XPS) using a spectrometer equipped with an electron energy analyzer (Scienta R3000) and a twin crystal monochromatized Al Kα ($h\nu = 1486.6$ eV) source (Vacuum Generators). All spectra were collected at room temperature and in normal emission geometry. The overall energy resolution was ~0.4 eV, and the Fermi level was calibrated using a polycrystalline Ag reference. The pressure in the spectrometer chamber was in the low 10^{−10} mbar range.

Electrochemical experiments

All electrochemical (EC) experiments were performed in a 3-compartment electrochemical cell using a BioLogic SP-300 potentiostat. Pt wire (PINE, 99.99%, 0.5 mm in diameter) and saturated calomel electrode (PINE, Hg/Hg₂Cl₂, 4 M KCl) were used as the counter and reference electrodes, respectively. The densified specimens (cylindric pellets of 8 mm in diameter) were used as working electrodes. Measurements were performed in Ar-saturated 0.1 M HClO₄ solution, prepared by dilution of 70% (by mass) HClO₄ (Sigma Aldrich, 99.999% metal basis) in ultrapure water (Milli-Q® Synthesis A10, Millipore; resistivity of 18.2 MΩ cm). Purging with argon (purity grade 5.0) for 30 min prior to each experiment was carried out in order to de-aerate the electrolyte.

To estimate the initial OER activity of the synthesized materials, linear sweep voltammetry (LSV) was done ($E_{\max} = 2.1$ V_{RHE}; sweep rate of 5 mV s^{−1}), followed by cyclic voltammetry (CV, $E_{\max} = 1.0$ V_{RHE}; sweep rate of 50 mV s^{−1}; 50 cycles) to monitor oxidation/reduction processes and remove possible contaminants from the surface. The measurement parameters were chosen in order to avoid the dissolution of Pt, which occurs at potentials higher than 1.1 V_{RHE}.^{25,42,43} The current densities were normalized to the geometrical surface area of the used specimens (0.204 cm²). The potential values were expressed *versus* reference hydrogen electrode (RHE). To avoid the incorrect voltammetry response due to the ohmic drop between working and reference electrodes as a result of solution resistance (R_u), the iR -correction was carried out. The R_u values were obtained from Electrochemical Impedance Spectroscopy (EIS) measurements. In order to control OER-activity changes during prolonged OER, chronopotentiometry (CP) was carried out at the benchmarking current density of 10 mA cm^{−2} for 2 h.^{44–47} Additionally, LSVs were measured after the CV pre-treatment and after one and two hours of CP experiment. The complete sequence of CV pre-treatment and the following CP will be referred in the text as “standard OER experiment”. The concentrations of the dissolved elements were determined by taking electrolyte aliquots at the end of the EC experiment. Elemental analysis was made *via* inductively coupled plasma-optical emission spectrometry (ICP-OES 5100 SVDV, Agilent).

Computational part

Electronic structure calculations were performed by using two first-principles all-electron full-potential methods. Both full-



potential local orbital (FPLO)⁴⁸ and Fritz-Haber-Institute *ab initio* molecular simulations (FHI-aims)⁴⁹ methods employ atom-centered numerical orbitals. The local density approximation (LDA) as parameterized by Perdew and Wang⁵⁰ and generalized gradient approximation (GGA) in the formulation of Perdew–Burke–Ernzerhof⁵¹ were used to include exchange–correlation effects. Convergence with respect to Brillouin zone sampling was checked carefully.

The Pt 4f shifts in M₂Pt compounds with respect to elemental Pt were calculated using the so-called delta self-consistent-field (delta SCF) approach.⁵² The 4f electron binding energy for a Pt atom in a compound is approximated as:

$$BE_{4f} = E_{\text{tot}}(4f^{13}) - E_{\text{tot}}(4f^{14}),$$

where $E_{\text{tot}}(4f^n)$ is the total energy of the compound with one Pt atom forced to have n electrons in its 4f shell. The Pt atom constrained to have 13f electrons acts as an impurity atom, thus a super cell is necessary to reduce the superficial impurity–impurity interactions. Since charged unit cells cannot be used in calculations adopting the periodic boundary conditions, the electron removed from the core has to be compensated. In our fully-relativistic FPLO calculations,^{53,54} this electron is placed in the valence bands. The 4f level shift to be compared with the XPS measurements is then obtained from the difference of binding energies:

$$\delta(BE_{4f}) = BE_{4f}(\text{M}_2\text{Pt}) - BE_{4f}(\text{Pt}).$$

This so-called final-state theory is more accurate than just looking at the difference between the energy levels of the Pt 4f in M₂Pt and Pt (usually referred to as initial-state theory), because the effects of the core hole (final-state effects) are considered.⁵⁵

The combined topological analysis of the electron density (ED) and electron localizability indicator (ELI) was applied to investigate the chemical bonding features of the title compounds in position space. The topological analysis of ED forms the basis of the quantum theory of atoms in molecules (QTAIM).⁵⁶ ELI was calculated in the ELI-D representation^{57–59} using an interface to the FHI-aims method.⁶⁰ The basin intersection technique was used to determine which atoms participate in a bond by contributing how many electrons.⁶¹ The topological analysis was carried out by employing the program DGrid.⁶² In a binary compound X_pY_q the bond fractions with respect to elements can be defined as:

$$p(X) = n_b^X/n_b, \quad p(Y) = n_b^Y/n_b,$$

where n_b is the number of electrons in the bond basin and n_b^X is the total number of electrons contributed to this bond by the atoms of element X.

Results and discussion

The binary compounds M₂Pt (M = Al, Ga, In, Sn) crystallize with *anti*-CaF₂ type of structure.^{63,64} The Pt atom is surrounded by eight M atoms, forming a cube. Filled and empty cubes are

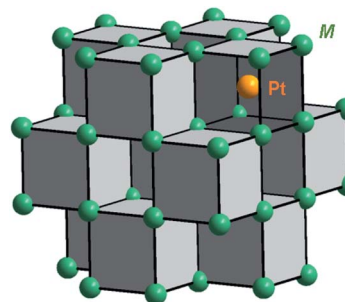


Fig. 1 *Anti*-CaF₂ type crystal structure of the M₂Pt compounds.

altered in a column, sharing the common faces, and such columns fill the unit cell (Fig. 1). Each M atom has four Pt nearest neighbours, forming a tetrahedron.

The X-ray powder diffraction patterns confirmed the single-phase character of the prepared materials (Fig. 2), and were indexed using unit cells with lattice parameters: $a(\text{Al}_2\text{Pt}) = 5.9270(1) \text{ \AA}$ < $a(\text{Ga}_2\text{Pt}) = 5.9309(1) \text{ \AA}$ < $a(\text{In}_2\text{Pt}) = 6.3705(3) \text{ \AA}$ < $a(\text{Sn}_2\text{Pt}) = 6.4322(3) \text{ \AA}$, following the expected trend according to the increasing atomic size of the main-group elements M (Al < Ga < In < Sn).

The metallographic studies confirmed the homogeneity of the samples (Fig. S1 and S2†). Interestingly, although Pt and the counterpart elements M look metallic silvery,⁶⁶ the intermetallic compounds Al₂Pt, Ga₂Pt and In₂Pt have a goldish luster,⁶⁷ whereas Sn₂Pt remains metallic grey. The energy dispersive X-ray spectroscopy analysis of the densified materials reveals the molar ratios of Al : Pt = 67.0(5) : 33.0, Ga : Pt = 63.8(9) : 36.2,

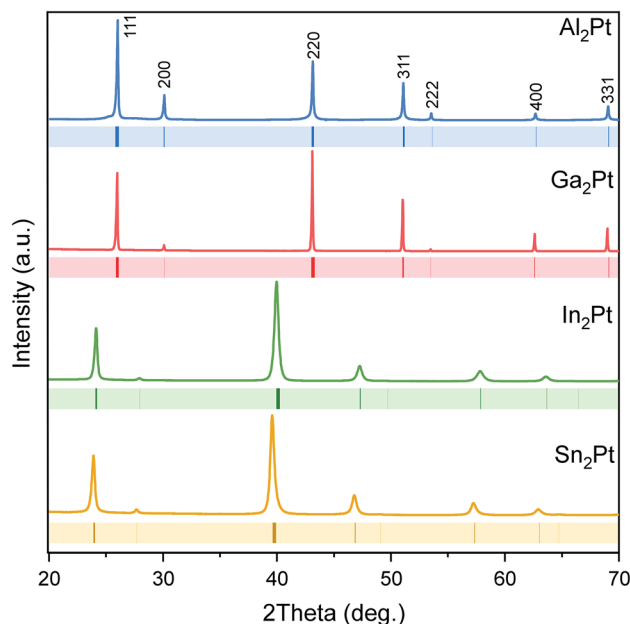


Fig. 2 Powder X-ray diffraction patterns of the single-phase M₂Pt samples. Peak positions of the isostructural M₂Pt compounds⁶⁵ are shown with coloured ticks below the experimental PXRD patterns.



Table 1 QTAIM charges and contributions of M and Pt atoms to ELI-D bond basins in M_2Pt compounds

		Al_2Pt	Ga_2Pt	In_2Pt	Sn_2Pt
QTAIM charge	Pt	−3.52	−1.26	−1.24	−1.24
	M	1.76	0.63	0.62	0.62
Contribution to the ELI-D basin	Pt	0.84	0.46	0.26	0.41
	M	0.29	0.66	0.19 ^a	0.85
Bond fraction	$p(Pt)$	0.74	0.41	0.41	0.33
	$p(M)$	0.26	0.59	0.59	0.67

^a For each In atom in the three-center bond In–Pt–In.

In : Pt = 65.0(3) : 35.0 and Sn : Pt = 66.3(2) : 33.7 (at%), close to the intended composition M_2Pt .

Chemical bonding in M_2Pt compounds was investigated by employing the method of position-space analysis of the electron density (ED) and the electron localizability indicator (ELI-D). The topological analysis of the electron density revealed charge transfer from M to Pt atoms for all M_2Pt compounds (Table 1). In Ga_2Pt , In_2Pt and Sn_2Pt the amount of charge transfer is practically the same and significantly smaller than that in Al_2Pt . This finding agrees with the electronegativity values of the M atoms: 1.714, 2.419, 2.138 and 2.298 for M = Al, Ga, In and Sn, respectively.⁶⁸ The relatively large effective charges indicate that contributions of the ionic interactions are important for the cohesiveness of the M_2Pt compounds.

The topological analysis of the ELI-D fields yielded only one type of two-atom M–Pt bonds in Al_2Pt , Ga_2Pt and Sn_2Pt . However, in In_2Pt one type of three-atom In–Pt–In bonds was found (Fig. S3†). To obtain individual atom contributions to the bond electrons of a bond basin, the basin intersection technique was applied and the bond fractions for M and Pt (revealing bond polarities) were evaluated. The results show that the Pt contribution is three times that of Al in Al_2Pt , but in the other M_2Pt compounds the bond polarity is reversed: M atom contributions are 1.5 (Ga, In) and 2.0 (Sn) times that of Pt (Table 1). This bond polarity reversal reflects the difference between Al_2Pt and the other M_2Pt compounds regarding the amount of charge transfer.

X-ray photoelectron spectroscopy (XPS) affirms the shifts of the Pt 4f core levels towards higher binding energies, *i.e.* by 1.12, 0.77, 0.42 and 1.02 eV for Al_2Pt , Ga_2Pt , In_2Pt and Sn_2Pt , respectively (Fig. 3). Noteworthy, for M_2Pt with M from the group 13, the shift of binding energies for Pt 4f core levels increases with decreasing the atomic radii of M. The Pt 4f core level shifts of M_2Pt with respect to elemental Pt were also computed by first-principles total energy calculations using the conventional cubic cell as the supercell. The experimentally observed trend for M = Al, Ga and In is well reproduced with calculated values being 1.18, 0.96 and 0.66 eV, respectively. The shift for Sn_2Pt was found to be 1.25 eV, larger than that for Al_2Pt . The shift to higher binding energies in M_2Pt occurs together with a charge transfer from the M atoms to Pt (*i.e.*, negatively charged Pt), a result previously observed in Be_5Pt^{69} and Ga–Pd intermetallic compounds.⁷⁰ Although the core level shifts to higher binding energies are usually associated with a positive

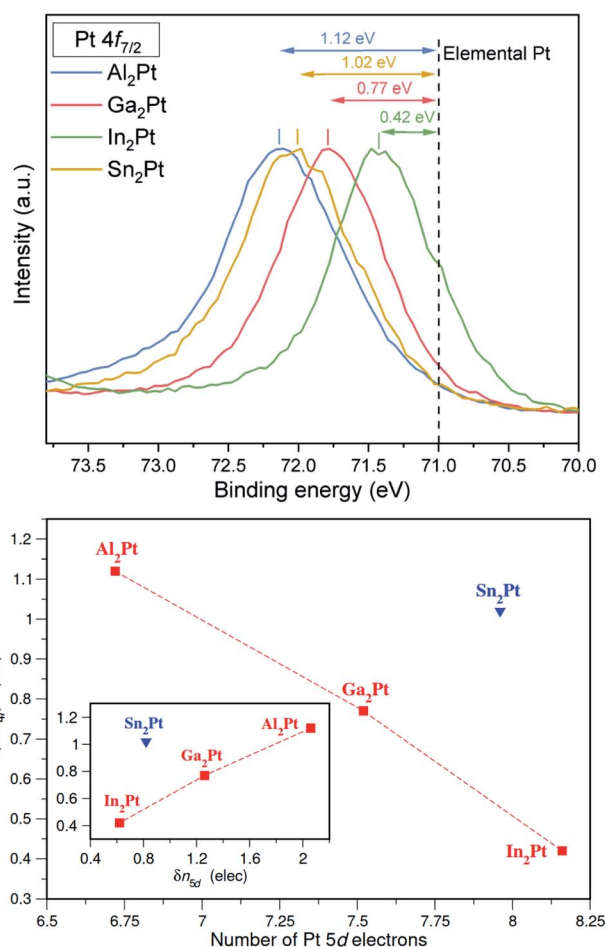


Fig. 3 (top) Normalized XPS spectra of Pt 4f core levels in M_2Pt compounds. Black dashed line corresponds to the binding energy of Pt 4f_{7/2} core level in elemental Pt. For clarity, only the Pt 4f_{7/2} parts of the Pt 4f doublets are presented. (bottom) The Pt 4f core level shifts, measured by XPS, plotted against (i) the number of Pt 5d electrons, determined by the ELI-D analysis (main figure), (ii) shift in Pt 5d subshell occupancy (inset). The dashed lines are used only to guide the eye.

valence state of the atom, the situation is in general more complicated.⁷¹ In addition to the charge transfer effects, the final-state screening due to conduction electrons also play an important role. However, the ELI-D analysis provides an alternative explanation for the case of M_2Pt compounds based on the number of electrons in the 5d subshell. ELI-D is capable of resolving the shell structure in free atoms, meaning the ELI-D basins are organized according to the principal quantum number. This property groups the 5d electrons of Pt together with the 5s and 5p electrons. In the case of a molecule or solid, the atomic shell structure is still maintained for the core electrons, and the valence electrons form the chemical bonds as a result of atomic interactions. Consequently, Pt 5d electrons show up in the core region when the ELI-D is computed for a Pt-containing compound. Since the basins accommodating the core electrons can be obtained for each atom, the total number of core electrons for each Pt atom in a compound is available from the topological analysis of the ELI-D. A total of 68 electrons



(54 up to Xe configuration plus 14 for the 4f) always belong to the core, therefore, the difference between the total number of core electrons and 68 gives the number of 5d electrons, n_{5d} , for that Pt atom. Fig. 3 (bottom) plots the XPS Pt 4f core level shifts against n_{5d} computed for the title compounds. A linear trend is clearly observed for M_2Pt when M is a group 13 element, Al, Ga, In. Sn belonging to group 14 with a formal valence of 4+ causes Sn_2Pt to be an outlier. The more electrons in the 5d subshell, the smaller the 4f core level shift is. This implies that 5d electrons play a crucial role in screening the core hole and providing the relaxation of the electronic structure after the 4f electron is ejected out of the 4f subshell. A better representation of these results can be achieved by taking the n_{5d} obtained for elemental Pt as reference and defining

$$\delta n_{5d}(M_2Pt) = n_{5d}(Pt) - n_{5d}(M_2Pt),$$

so that only shifts obtained with respect to the according quantity of the elemental Pt can be compared with each other. The resulting plot is presented in the inset of Fig. 3 (bottom) with the reference value $n_{5d}(Pt)$ being 8.78. This figure suggests that for $M = Al, Ga$ and In , we can write $\delta(BE_{4f}) \sim \delta n_{5d}$, so that the shift in 5d occupancy, δn_{5d} , may be used as a predictor of Pt 4f core level shifts.

The electronic state of Pt in the isostructural M_2Pt ($M = Al, Ga, In$) compounds differs slightly. To clarify if this influences their electrocatalytic activity for OER, the following EC experiments were carried out: (i) cyclic voltammetry (CV) in order to monitor the possible oxidation/reduction processes and accessibility of Pt active sites on the surface, and (ii) chronopotentiometry (CP) at current density of 10 mA cm^{-2} for 2 h, following the conventional benchmarking protocol.^{44–47}

The recorded cyclic voltammograms for M_2Pt ($M = Al, Ga, In$) exhibit both oxidation and reduction features in the so-called hydrogen underpotential deposition (H_{UPD}) region ($0.05\text{--}0.4 \text{ V}_{RHE}$ for elemental Pt^{72-74}), showing the reversibility of the proton adsorption process (Fig. 4). Furthermore, the areas, corresponding to the adsorption/desorption of hydrogen on Al_2Pt , Ga_2Pt and In_2Pt electrode surfaces, increase with increasing the number of cycles (Fig. S4†). This increase is related to surface cleaning and reconstruction, leading to enhanced accessibility of Pt sites for catalysis. After fifty cycles, these areas become practically unchanged: the increase between the two last cycles is only 0.5%, 0.8% and 0.09% compared to the maximum areas for Ga_2Pt , In_2Pt and Sn_2Pt , respectively.

Further oxidation features of M_2Pt with M from the group 13 were found on the anodic scans after the H_{UPD} region (potentials above 0.4 V_{RHE} , Fig. 4). Contrary to the Al_2Pt compound with almost unrecognizable surface oxidation, CV of In_2Pt is characterized by two oxidation peaks with potential onsets at 0.55 and $ca. 0.9 \text{ V}_{RHE}$. They correspond to the electron transfer during the OH adsorption and its further oxidation to atomic oxygen, respectively, and resemble the behaviour of elemental Pt.^{74,75} For Ga_2Pt only an oxidation peak around 0.9 V_{RHE} was detected, which, most probably, coincides with OH_{ad} oxidation, whereas adsorption of OH cannot be clearly differentiated from

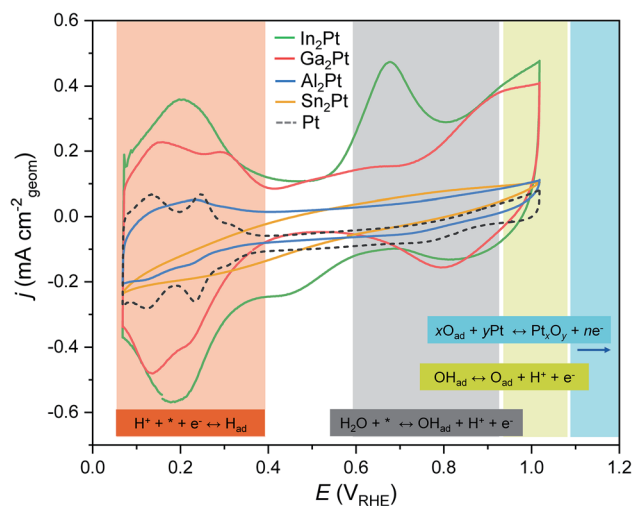


Fig. 4 The 50th CV cycles ($0.05\text{--}1.0 \text{ V}_{RHE}$; 50 mV s^{-1}) for M_2Pt ($M = Al, Ga, In, Sn$) compounds. Shaded areas correspond to the characteristic CV regions, known for fcc Pt.⁷⁴ The corresponding equations are highlighted with the same colours (* denotes the active site).

relatively large capacitance current. Analysis of the areas below the oxidation peaks, resembling OH adsorption, shows that the surface of In_2Pt is the most favourable for OH adsorption.

On the cathodic scans, the reduction peaks occur at $ca. 0.8$ and 0.85 V_{RHE} for Ga_2Pt and In_2Pt , respectively, that are higher potentials than for metallic Pt, for which the reduction peak occurs at $ca. 0.75 \text{ V}_{RHE}$.^{20,74} The similar areas below those peaks for Ga_2Pt and In_2Pt ($0.216 \text{ mA cm}^{-2} \text{ V}^{-1}$ and $0.218 \text{ mA cm}^{-2} \text{ V}^{-1}$, respectively), indicate that a comparable amount of species is reduced at both surfaces.

For Sn_2Pt , neither hydrogen adsorption, nor surface oxidation features were observed (Fig. 4). This reveals an absence of electron transfer on the surface or that the number of electrons being transferred is not enough to differentiate these features.

It is known that transient operation is very harmful to electrode stability and leads to the dissolution even of noble metals.^{25,76} To monitor the possible dissolution, the *ex situ* elemental analysis of the $HClO_4$ solution after the electrochemical experiments was carried out. No dissolved Pt was identified (detection limit 0.05 mg L^{-1}) in any of the analyzed electrolyte probes. However, after CV experiment with In_2Pt some amount of In (0.14 mg L^{-1}) was detected, whereas for other M_2Pt anode materials the quantities of the M component did not exceed the detection limit (0.05 mg L^{-1}).

The detected amount of In in the electrolyte together with the OH adsorption features on the CV of In_2Pt give a hint on the on-going surface processes. Upon the applied potential, the water molecules cover the surface of the anode (while protons move to the cathode) and approach both type of atoms: (i) the positively charged M form the corresponding hydroxide species, which may dissolve (this explains the pronounced peak of OH adsorption, whereas the OH reduction peak was not clearly distinguished), and (ii) the negatively charged Pt atoms, where their adsorption gives rise to the first step of the OER.^{8–10}



Summarizing, the cyclic voltammetry in the potential range 0.05–1.0 V_{RHE} does not cause noticeable Pt dissolution from M₂Pt, however, it leads to the surface changes of the electrode materials.

In order to estimate the OER activity, linear sweep voltammetry (LSV) was performed and the overpotential, necessary to reach the current density of 10 mA cm⁻² was used as a benchmark activity marker for fundamental studies. The OER activity follows a trend In₂Pt > Ga₂Pt > Al₂Pt, reaching 10 mA cm⁻² at the overpotentials (η_{10}) of 520, 570, 730 mV, respectively. In the case of Sn₂Pt anode, current density of 10 mA cm⁻² was not reached even at the maximum applied potential ($E_{\max} = 2.1$ V_{RHE}, Fig. 5). Therefore, only M₂Pt compounds of Al, Ga and In can be considered as OER-active materials. It is not out of notice that the obtained η_{10} values are higher than those of the best Ir- and Ru-based oxide electrocatalysts (Table S1,† e.g. IrO_x/SrIrO₃, 270 mV;¹⁸ nanoparticulated Cr_{0.6}Ru_{0.4}O₂, 178 mV¹⁹). However, η_{10} of elemental Pt is 745 mV,^{20,25,35} and the reduced overpotentials of the M₂Pt (M = Al, Ga, In) compounds agree with the idea that modifying the electronic structure of Pt can improve its inherent activity. Furthermore, the OER overpotential values depend strongly on the parameters of CV pre-treatment, cf. η_{10} is equal to 580 mV for Al₂Pt after a different pre-treatment.³⁵

The surface changes after the CV pre-treatment were monitored by XPS. The Pt 4f core levels shift towards lower binding energies by 0.72, 0.55, 0.42 and 0.38 eV (compared to pristine M₂Pt), for Al₂Pt, Ga₂Pt, In₂Pt and Sn₂Pt, respectively (Table S2 and Fig. S5†). The Pt 4f core levels become closer to that of elemental Pt, visualizing the change of Pt electronic state at the surface. The width of the XPS peaks clearly reveals a mixture, consisting of intermetallic M₂Pt and freshly formed solid solution M_xPt_{1-x} with a Pt state closer to the elemental one.

To check the preservation of the OER activity over time, the chronopotentiometry (CP) study at 10 mA cm⁻² was performed (Fig. S6†). The compounds Ga₂Pt and In₂Pt almost reach the steady-state after the first hour of CP: similar LSVs were observed after first and second hours of CP (Fig. 5). Contrary to them, Al₂Pt and Sn₂Pt are still activating after the second hour of the anodic treatment, meaning re-arrangements are still ongoing on their surfaces. The OER activity improves after the CP treatment for all M₂Pt compounds. The following η_{10} values were obtained after 2 h of CP: 510 mV (In₂Pt), 540 mV (Ga₂Pt), 610 mV (Al₂Pt) and 840 mV (Sn₂Pt). No Pt was detected in the electrolytes after the complete standard OER experiments. However, measurable concentrations of Al (0.30 mg L⁻¹), Ga (1.99 mg L⁻¹), In (3.36 mg L⁻¹) clearly reveal the leaching of the main-group element from the material upon anodic treatment. Noteworthy, Sn was not dissolved under such conditions. The observed trend of the dissolution rates for M₂Pt (M = Al, Ga, In) correlates inversely with the computed formation energies: 0.895, 0.577, 0.448 eV per atom for Al₂Pt, Ga₂Pt and In₂Pt, respectively (GGA calculations). Higher formation energy implies higher stability and thus lower dissolution rate. The formation energy of Sn₂Pt is actually the lowest, 0.414 eV per atom, however most probably the formation of a passivating SnO₂ layer on the surface prevents the leaching of Sn. Based on these results, the M₂Pt (M = Al, Ga, In) compounds should be considered as precursors for formation of OER-active materials. Therefore, an understanding of their chemical behaviour under OER conditions and, as a result, the state of the freshly generated surface is of extreme importance.

One of the contributions to the improved OER activity of the M₂Pt (M = Al, Ga, In) materials may be the higher dissolution rate of the main group element (In > Ga > Al > Sn), yielding more Pt on the surface accessible for adsorbents and, correspondingly, higher surface area and higher current densities can be reached at the same potential values (inset on Fig. 5). But at the same time the dissolution of the counterpart element and the restructuring of the surface give rise to a more active surface, due to the formation of the mixed spatial arrangement of the intermetallic compound and the *in situ*-formed active M_xPt_{1-x} phase. This agrees with additional shifts of the Pt 4f core levels on the XPS spectra for all specimens after the standard OER experiment (Fig. 6 and Table S2†). The Pt 4f core level shifts for Al₂Pt and Sn₂Pt with respect to elemental Pt are 0.14 and 0.36 eV, respectively. The Pt 4f core levels for Ga₂Pt and In₂Pt coincide with that for elemental platinum. However, these materials are more active than elemental Pt!

The (partial) dissolution of the constituent components from the anode surface is known as one of the strategies to improve the electrocatalyst performance. For example, the superior activity of IrO_x/SrIrO₃ originates from Sr leaching and forming of adsorption sites similar to those in IrO₃ or IrO₂.¹⁸ Also, the intermetallic compound Hf₂B₂Ir₅ with a cage-like type of structure self-improves its OER activity through near-surface oxidation, including Hf leaching and the controlled dynamic *in situ* formation of IrO_x(OH)_y(SO₄)_z particles.⁷⁷ These thoughts agree with the electrochemical results and the elemental analysis of the electrolyte (Fig. 5): higher dissolution of M (M = Al,

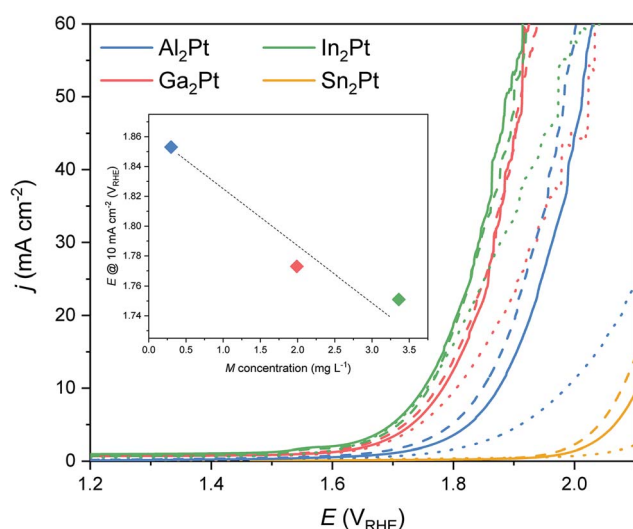


Fig. 5 Linear sweep voltammetry for Al₂Pt, Ga₂Pt, In₂Pt and Sn₂Pt anode materials: after CV (dotted), 1 h of CP (solid) and 2 h of CP (dashed). (inset) Relationship between potential at $j = 10$ mA cm⁻² after 2 h CP experiment and the amount of dissolved M for the M₂Pt (M = Al, Ga, In).



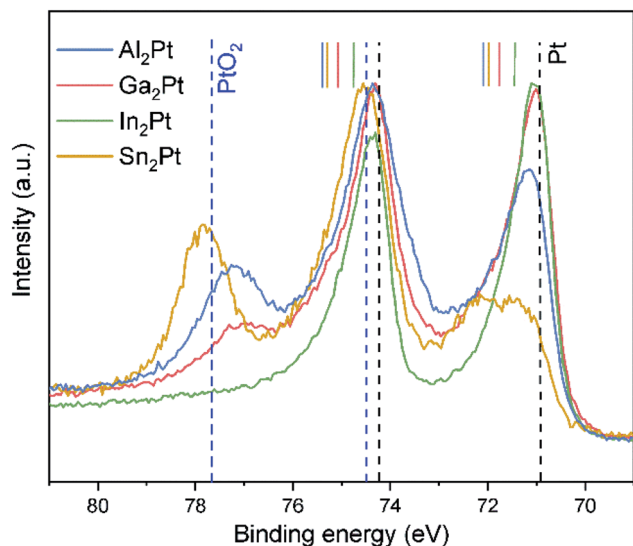


Fig. 6 Normalized XPS of Pt 4f core levels in the Al_2Pt , Ga_2Pt , In_2Pt and Sn_2Pt samples after the standard OER experiment. The positions for those core levels in the pristine M_2Pt are marked with the vertical ticks of the same color. The vertical dashed lines represent the binding energies for Pt (black) and PtO_2 (blue).

Ga, In) seems to lead to an increased amount of *in situ*-formed highly active Pt on the surface and improved OER performance.

Pt oxides are present on the surfaces of Al_2Pt , Ga_2Pt and Sn_2Pt after the standard OER experiment. The intensities of the Pt 4f core levels characteristic for PtO_x , compared with the peak intensities of the intermetallic/metallic ones, follow a reversed trend with respect to the OER-activity: $\text{Sn}_2\text{Pt} > \text{Al}_2\text{Pt} > \text{Ga}_2\text{Pt}$. Pt oxides are not formed on the surface of In_2Pt .

The *in situ*-formed more active Pt species participate in two concurrent processes: (i) as active sites for OER, revealed by the activation of the material with electrochemical treatment and increasing surface area of the active sites, and (ii) in oxidation at high anodic potentials yielding the Pt oxides. This gives rise to a dynamic state of the surface, composed of the intermetallic M_2Pt , freshly formed OER-active solid solution $\text{M}_x\text{Pt}_{1-x}$ and platinum oxides.

The details about the electronic and chemical states of M were obtained from XPS spectra of the corresponding core levels (Al 2s, Ga 2p, In 3d and Sn 3d, Fig. S7†). Initially, the surface of all specimens is covered by their oxides and in the cases of Ga_2Pt and In_2Pt also by their hydroxides $\text{Ga}(\text{OH})_3$ and $\text{In}(\text{OH})_3$, respectively. After the EC experiments, the detection of the Al 2s core level is hampered by its significantly reduced amount due to the pronounced dissolution and the small cross section of this orbital.^{78,79} On the other hand, the XPS spectra of Ga 2p_{3/2}, In 3d_{5/2} and Sn 3d_{5/2} core levels clearly reveal the presence of Ga_2O_3 , traces of $\text{Ga}(\text{OH})_3$, $\text{In}(\text{OH})_3$ and SnO_2 on the M_2Pt (M = Ga, In, Sn) surfaces, respectively. It is important to mention that SnO_2 is well known to be electrochemically inert,^{80–82} and the coverage of the Sn_2Pt sample by the poorly conductive SnO_2 hinders the electron transfer and leads to OER inactivity of Sn_2Pt .

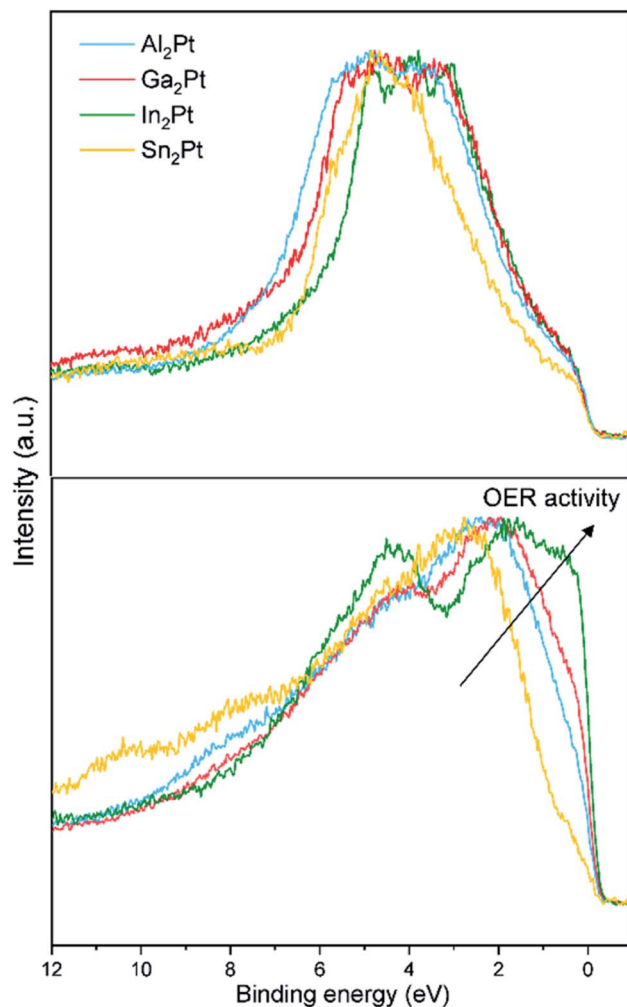


Fig. 7 Normalized experimental XPS VBs of M_2Pt (M = Al, Ga, In, Sn): as-synthesized state (top) and after the standard OER experiment (bottom).

The experimentally obtained valence bands (VB) of the initial M_2Pt compounds possess similar features (Fig. 7). Their comparison with the calculated density of states (DOS) reveals the dominant contribution of the Pt 5d states (Fig. S8†). The 5d partial DOS (pDOS) curves consist of distinct peaks with relatively narrow widths emphasizing their localized or atomic-like nature. The narrow widths imply weak hybridization with the M atom p states. This feature is in line with the suggestion that the 5d electrons play a significant role in screening the core-hole effects in the Pt 4f XPS experiments. The widths of the VB (as deduced from Fig. 7) are approximately 4.0, 4.5 and 5.0 eV for In_2Pt , Ga_2Pt and Al_2Pt , respectively. This ordering of the compounds agrees with that based on the spread of the 5d pDOS peaks. The VB width of Sn_2Pt is comparable to that of In_2Pt in both experiment and calculation. The catalytic activity of transition metal containing compounds is usually understood within the d-band model.⁸³ According to this model, the closer the center of the d-band to the Fermi level, the better the activity of the compound is. The valence electrons are mainly used for forming chemical bonds in the compound, leaving the



d electrons as the best means to hybridize with the electrons of the molecules to be adsorbed. Hence the features of the d-band are crucial in determining the nature of the transition metal – adsorbate interaction.^{84–86} The computed 5d-band centers referred to the Fermi level (set to 0 eV) are -3.39 , -3.87 and -4.12 eV for In_2Pt , Ga_2Pt and Al_2Pt , respectively, in full agreement with the observed OER activity order. The value for Sn_2Pt is -4.04 eV, however its OER inactivity is largely due to the formation of a SnO_2 passivation layer. This highlights the shortcomings of the d-band model which considers only the initial characteristics of the valence band; a more realistic approach should take into account the chemical state of the surface under reaction (OER, here) conditions.^{87,88}

The activity is certainly influenced by the leaching of the counterpart element and formation of the Pt-rich active near-surface layer upon OER conditions. This leads to the drastic changes of the valence bands after the standard OER experiment, which resembles the density of states (DOS) of elemental Pt (Fig. 7 and S8†). The Fermi cut for In_2Pt is the most pronounced, followed by Ga_2Pt , Al_2Pt and Sn_2Pt , indicating that the conductivity of the samples also follows the mentioned order, due to the decreasing number of states at the Fermi level. This reveals the increasing amount of *in situ*-formed $\text{M}_x\text{Pt}_{1-x}$ (electronically close to the elemental Pt), in good agreement with the stronger leaching of the M ($\text{In} > \text{Ga} > \text{Al}$). The Fermi cut is another feature, which correlates well with the activity of the samples after the standard OER experiment, and follows the same trend: $\text{In}_2\text{Pt} > \text{Ga}_2\text{Pt} > \text{Al}_2\text{Pt} > \text{Sn}_2\text{Pt}$.

Metallographic studies reveal that the surfaces of M_2Pt are still compact, meaning that the leaching takes place only in the near-surface region. The leaching is also evidenced by the mapping of the elements, showing a pronounced depletion of the EC-treated area in M (enrichment in Pt) for M_2Pt ($\text{M} = \text{Al}$,

Ga , In) compounds (Fig. 8), in agreement with ICP-OES data (see above). Quantitatively, the In_2Pt material shows the most pronounced Pt enrichment of the treated area, while for Sn_2Pt there is no difference in Pt content from exposed and non-exposed to electrolyte areas, which is also consistent with the fact that Sn was not found in the electrolyte after electrochemical experiments, and was present on the surface in form of SnO_2 .

The experimentally obtained, normalized X-ray intensities of the M_2Pt samples at the acceleration voltages of 5, 10 and 27 kV after the standard OER experiment were compared with the calculated, normalized X-ray intensities of the hypothetically homogeneous M_2Pt materials (Fig. 8 and Table S3†). The experimental intensities of $\text{Al K}\alpha$, $\text{Ga L}\alpha$ and $\text{In L}\alpha$ lines are lower than the theoretical values, proving again the reduced amount of these elements on the surfaces.

From the quantitative EDXS analysis, the measured intensity of the $\text{Al K}\alpha$ line in Al_2Pt reveal a gradual depletion of Al content from bulk to the near-surface regions. However, the simulated pattern shows an opposite tendency of the $\text{Al K}\alpha$ line. This means that the Al dissolution overcompensates the composition-independent effect and confirms the gradual changes in concentration from the surface in contact with electrolyte towards the bulk of the material, being, however, no longer so pronounced at a depth of $2.2\ \mu\text{m}$ (obtained with acceleration voltage of 27 kV). The difference between the calculated intensities and the measured ones for Ga_2Pt indicates a significant dissolution of Ga into the electrolyte, which happens even at a depth of $1.8\ \mu\text{m}$ (probed with acceleration voltage of 27 kV, Table S3†). Similarly, the small intensities of $\text{In L}\alpha$ lines for all acceleration voltages show a pronounced depletion in In for In_2Pt . The measured intensities for the $\text{Sn L}\alpha$ lines are comparable with the calculated ones for all

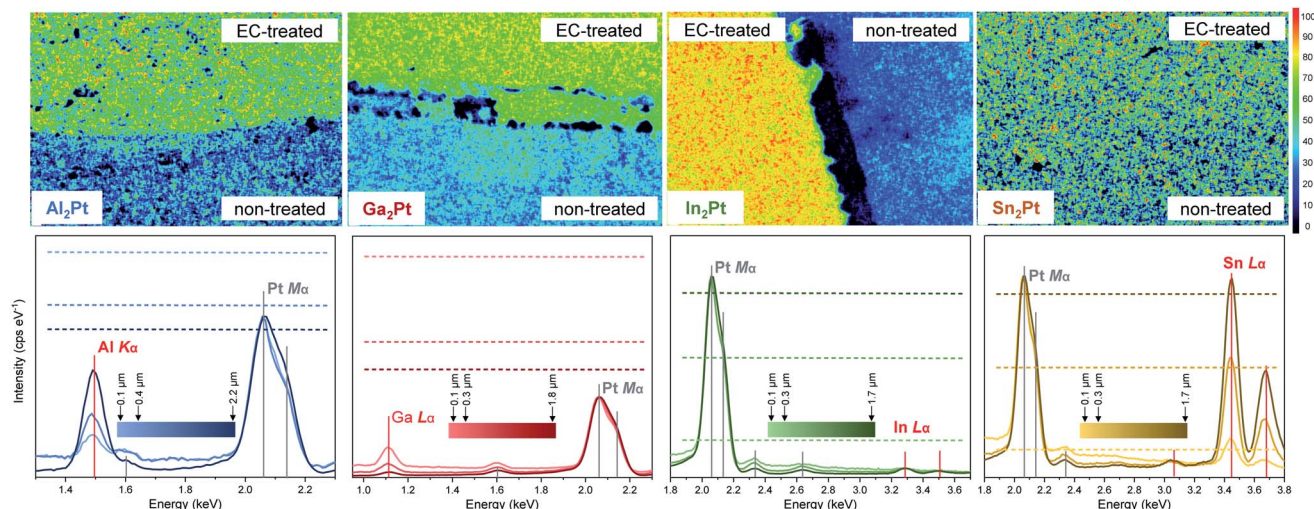


Fig. 8 Pt $\text{M}\alpha$ intensity maps (acceleration voltage 27 kV) of M_2Pt samples (top). The maps (colour code right) represent relative changes of the Pt concentration close to the border between EC-treated and non-treated regions of material. EDXS spectra normalized to the Pt $\text{M}\alpha$ line (bottom). The spectra have been measured on the EC-treated materials with three different acceleration voltages (5 kV, 10 kV, 27 kV) to vary the penetration depth of the electron beam (colour bars). The relative intensity of the respective X-ray line of the element M ($\text{M} = \text{Al}$, Ga , In , Sn) shows significant depth dependence compared to hypothetically homogenous material M_2Pt . The relative intensities for M_2Pt (dashed lines) are calculated by using the ZAF matrix correction model.



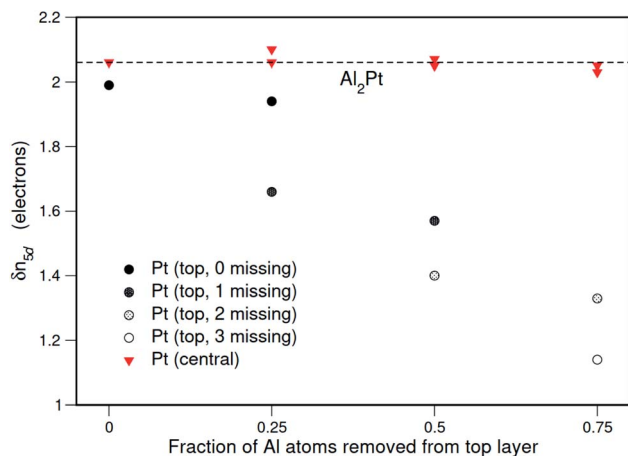


Fig. 9 Calculated shifts in 5d occupancy as a function of the fraction of Al atoms removed from the top layer. The value for the bulk Al_2Pt is indicated by a dashed line. The elemental Pt corresponds to $\delta n_{5d} = 0$ by definition.

acceleration voltages, which means that the composition does not change for Sn_2Pt . This agrees with the fact that no Sn or Pt was found in the electrolyte after the EC experiments with Sn_2Pt .

In order to have a quantum chemical insight into the possible effects of the changes in Pt environment on the Pt electronic state, the Al_2Pt surfaces were investigated in detail by first-principles calculations. The surface energy calculations reveal that Al_2Pt (111) surface terminated by an Al–Pt–Al composite layer is energetically the most favorable one (Fig. S9†). Hence, this surface was chosen to investigate the shift of the Pt 4f core level as Al atoms were gradually removed from the top layer to mimic the leaching process. Since the deviation of the Pt 5d occupancy in M_2Pt from that in elemental Pt, $\delta n_{5d}(\text{M}_2\text{Pt})$, was found to act as a predictor of Pt 4f core level shifts, the ELI-D was calculated and analyzed to obtain the numbers of Pt 5d electrons for the Al_2Pt (2×2) (111) surfaces with surface unit cells containing 4, 3, 2 and 1 Al atoms on the top layer. This gradual removal of the top-layer Al atoms will decrease the number of the nearest Al neighbors of the subsurface-layer Pt atoms. The variation of the calculated 5d occupancy shifts, δn_{5d} , for the Pt atoms in the subsurface and central layers with the fraction of Al atoms removed from the top layer is shown in Fig. 9.

The Pt atoms at the center of the slab are found to behave as they do in the bulk, however the δn_{5d} values for the subsurface Pt atoms decrease as the nearest Al neighbors are removed. Note that δn_{5d} decreasing towards zero implies behavior becoming similar to that in elemental Pt. Also, from the inset of Fig. 3, $\delta(\text{BE}_{4f}) \sim \delta n_{5d}$, so it is reasonable to expect that with more Al atoms leaching the 4f core level binding energies of the Pt atoms near the surface regions will get closer to the value in elemental Pt, as was observed in the measured XPS spectra after the EC experiment.

The leaching of the main group element M, observed from ICP-OES and SEM results, leads to the change of the electronic

state and coordination environment of Pt compared to that in pristine M_2Pt (XPS spectra and DFT calculations). These modifications, giving rise to a mixture of Pt species at the surface, occurring during the surface restructuring upon oxidation/reduction treatment (CV) as well as within CP experiment. The compounds M_2Pt ($\text{M} = \text{Al}, \text{Ga}, \text{In}$) play a dual role: (i) as current collectors due to their good electrical conductivity, accompanied with the bulk stability of the electrode material, and (ii) as material precursors for the formation of an $\text{M}_x\text{Pt}_{1-x}$ phase at the surface and near-surface regions, which is catalytically more active than elemental Pt.

Conclusions

Isostructural compounds M_2Pt ($\text{M} = \text{Al}, \text{Ga}, \text{In}, \text{Sn}$) with *anti*- CaF_2 type of crystal structure were studied as electrocatalysts for the OER. The activity follows the trend $\text{In}_2\text{Pt} > \text{Ga}_2\text{Pt} > \text{Al}_2\text{Pt} > \text{Sn}_2\text{Pt}$, governed by the chemical nature of the counterpart elements M ($\text{M} = \text{Al}, \text{Ga}, \text{In}$) and their leaching rates under OER conditions. The leaching of M into the electrolyte creates a catalytically more active surface, composed of the remaining intermetallic M_2Pt and a $\text{M}_x\text{Pt}_{1-x}$ phase in the near-surface region (inferred from Pt concentration mappings and EDXS analysis as well as the shift of the Pt 4f core levels towards lower binding energies).

Therefore, the improved OER activity of these materials can be assigned to the larger number of Pt atoms on the surface (acting as active sites), and the enhanced reactivity of these sites, due to the modified electronic state of Pt compared with the pristine material. In the case of Sn_2Pt , the formation of SnO_2 as a passivation layer hinders electron transfer and leads to the poor OER performance.

Based on the presented results, the strategy of reducing the noble metal loading *via* use of intermetallic compounds and combining the stability of Pt with the ability of M to leach, can be considered as a promising one for the development of new water oxidation catalysts for proton exchange membrane (PEM) electrolysis. The M_2Pt compounds ($\text{M} = \text{Al}, \text{Ga}, \text{In}$) act as precursors for *in situ* formation of a dynamic surface with an electrochemically active $\text{M}_x\text{Pt}_{1-x}$ phase, while the bulk material acts as a current collector.

Conflicts of interest

There are no conflicts to declare.

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